

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







**Preferred Devices** 

# **Thyristor Surge Protectors**

## **High Voltage Bidirectional TSPD**

These Thyristor Surge Protective devices (TSPD) prevent overvoltage damage to sensitive circuits by lightning, induction and power line crossings. They are breakover-triggered crowbar protectors. Turn-off occurs when the surge current falls below the holding current value.

Secondary protection applications for electronic telecom equipment at customer premises.

### **Features**

- High Surge Current Capability: 80 Amps 10 x 1000 μsec, for Controlled Temperature Environments
- The MMT08B350T3 is used to help equipment meet various regulatory requirements including: Bellcore 1089, ITU K.20 & K.21, IEC 950, UL 1459 & 1950 and FCC Part 68.
- Bidirectional Protection in a Single Device
- Little Change of Voltage Limit with Transient Amplitude or Rate
- Freedom from Wearout Mechanisms Present in Non–Semiconductor Devices
- Fail-Safe, Shorts When Overstressed, Preventing Continued Unprotected Operation
- Surface Mount Technology (SMT)
- N Indicates UL Recognized File #E210057
- Pb-Free Package is Available

### MAXIMUM RATINGS (T.I = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Off–State Voltage – Maximum	$V_{DM}$	300	V	
Maximum Pulse Surge Short Circuit Current Non-Repetitive Double Exponential Decay Waveform (-25°C Initial Temperature) (Notes 1 and 2) 2 x 10 μsec 8 x 20 μsec 10 x 160 μsec 10 x 360 μsec 10 x 560 μsec 10 x 700 μsec 10 x 1000 μse	IPPS1 IPPS2 IPPS3 IPPS4 IPPS5 IPPS6 IPPS7	±250 ±250 ±150 ±150 ±100 ±100 ±80	A(pk)	
Non-Repetitive Peak On-State Current 60 Hz Full Sign Wave	I <sub>TSM</sub>	32	A(pk)	
Maximum Non–Repetitive Rate of Change of On–State Current Exponential Waveform, < 100 A	di/dt	±300	A/μs	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. Allow cooling before testing second polarity.
- Measured under pulse conditions to reduce heating.



### ON Semiconductor®

http://onsemi.com

### BIDIRECTIONAL TSPD (%) 80 AMP SURGE, 350 VOLTS





SMB (No Polarity) (Essentially JEDEC DO-214AA) CASE 403C

#### **MARKING DIAGRAM**



A = Assembly Location

Y = Year

WW = Work Week
RPCM = Device Code
■ Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMT08B350T3	SMB	2500/Tape and Reel
MMT08B350T3G	SMB (Pb-Free)	2500/Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Operating Temperature Range Blocking or Conducting State	T <sub>J1</sub>	-40 to +125	°C
Overload Junction Temperature – Maximum Conducting State Only	T <sub>J2</sub>	+175	°C
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

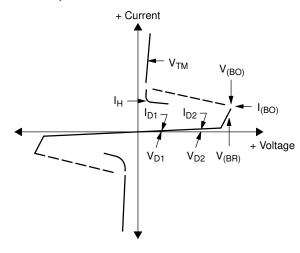
# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted) Devices are bidirectional. All electrical parameters apply to forward and reverse polarities.

Characteristics	Symbol	Min	Тур	Max	Unit
Breakover Voltage (Both polarities) $ (dv/dt = 100 \text{ V}/\mu\text{s}, \text{ I}_{SC} = 1.0 \text{ A}, \text{ Vdc} = 1000 \text{ V}) \\ (+65^{\circ}\text{C}) $	V <sub>(BO)</sub>		- -	400 412	V
Breakover Voltage (Both polarities) (f = 60 Hz, $I_{SC}$ = 1.0 A(rms), $V_{OC}$ = 1000 V(rms), $R_l$ = 1.0 k $\Omega$ , t = 0.5 cycle) (Note 3) (+65°C)	V <sub>(BO)</sub>	-	-	400 412	V
Breakover Voltage Temperature Coefficient	$dV_{(BO)}/dT_{J}$	_	0.12	_	V/°C
Breakdown Voltage (I <sub>(BR)</sub> = 1.0 mA) Both polarities	V <sub>(BR)</sub>	-	350	-	V
Off State Current ( $V_{D1} = 50 \text{ V}$ ) Both polarities ( $V_{D2} = V_{DM}$ ) Both polarities	I <sub>D1</sub> I <sub>D2</sub>	- -	_ _	2.0 5.0	μΑ
On–State Voltage ( $I_T$ = 1.0 A) (PW $\leq$ 300 $\mu$ s, Duty Cycle $\leq$ 2%) (Note 3)	V <sub>T</sub>	-	1.7	3.0	V
Breakover Current (f = 60 Hz, $V_{DM}$ = 1000 V(rms), $R_S$ = 1.0 k $\Omega$ ) Both polarities	I <sub>BO</sub>	-	475	-	mA
Holding Current (Both polarities) (Note 3) $V_S = 500 \text{ V; } I_T \text{ (Initiating Current)} = \pm 1.0 \text{ A (+65°C)}$	I <sub>H</sub>	150 130	270 -	- -	mA
Critical Rate of Rise of Off–State Voltage (Linear waveform, $V_D$ = Rated $V_{BR}$ , $T_J$ = 25°C)	dv/dt	2000	-	-	V/μs
Capacitance (f = 1.0 MHz, 50 Vdc, 1.0 V rms Signal) (f = 1.0 MHz, 2.0 Vdc, 1.0 V rms Signal)	C <sub>O</sub>	_ _	20 42	25 45	pF

<sup>3.</sup> Measured under pulse conditions to reduce heating.

# Voltage Current Characteristic of TSPD (Bidirectional Device)

Symbol	Parameter
I <sub>D1</sub> , I <sub>D2</sub>	Off State Leakage Current
$V_{D1}, V_{D2}$	Off State Blocking Voltage
V <sub>BR</sub>	Breakdown Voltage
V <sub>BO</sub>	Breakover Voltage
I <sub>BO</sub>	Breakover Current
I <sub>H</sub>	Holding Current
V <sub>TM</sub>	On State Voltage



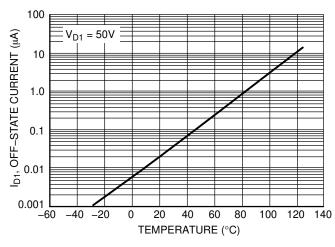


Figure 1. Typical Off-State Current versus Temperature

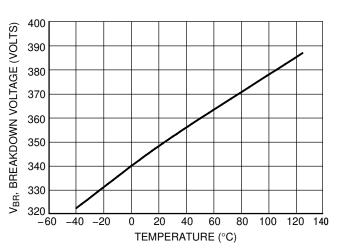


Figure 2. Typical Breakdown Voltage versus Temperature

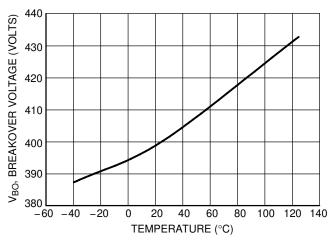


Figure 3. Maximum Breakover Voltage versus Temperature

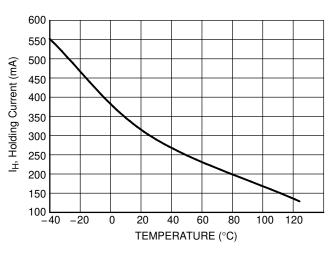


Figure 4. Typical Holding Current versus Temperature

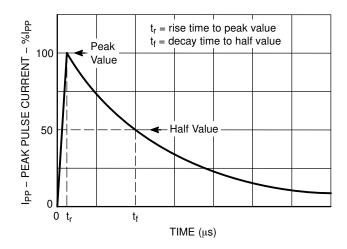


Figure 5. Exponential Decay Pulse Waveform

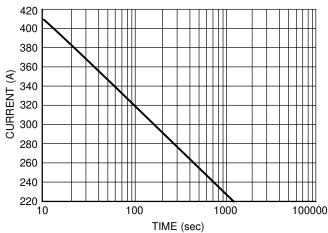
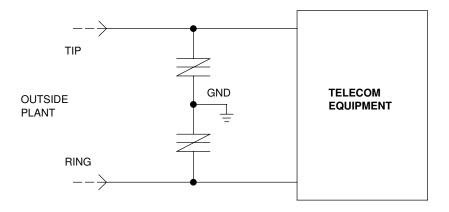
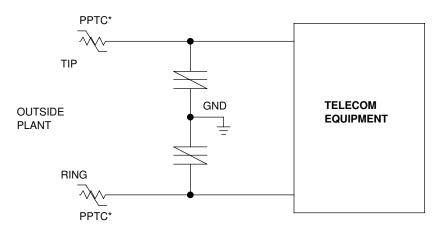
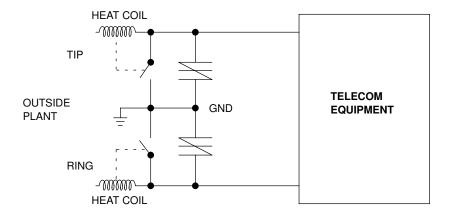


Figure 6. Peak Surge On-State Current versus Surge Current Duration, Sinusoidal Waveform



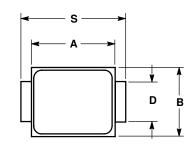


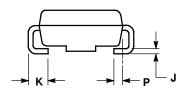
\*Polymeric PTC (positive temperature coefficient) overcurrent protection device

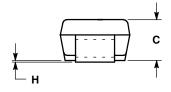


### PACKAGE DIMENSIONS

### **SMB** CASE 403C-01 ISSUE A



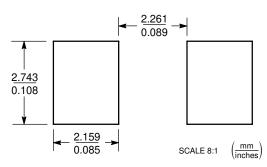




- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.160	0.180	4.06	4.57
В	0.130	0.150	3.30	3.81
С	0.075	0.095	1.90	2.41
D	0.077	0.083	1.96	2.11
Н	0.0020	0.0060	0.051	0.152
J	0.006	0.012	0.15	0.30
K	0.030	0.050	0.76	1.27
Р	0.020	0.020 REF		REF
S	0.205	0.220	5.21	5.59

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA **Phone**: 480–829–7710 or 800–344–3860 Toll Free USA/Canada **Fax**: 480–829–7709 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.